



# Product Change Notification



Product Group: SIL/Wed Nov 23, 2022/PCN-SIL-000407-2022-REV-0

## DG9424/5/6E Datasheet Update

**DESCRIPTION OF CHANGE:** Change of Turn-on time Full temp Max limit specification for 3V Single supply from 193 ns to 230 ns

**REASON FOR CHANGE:** Update limits more accurately

**EXPECTED INFLUENCE ON QUALITY/RELIABILITY/PERFORMANCE:** There will be no effect on performance, quality or reliability.

**PART NUMBERS/SERIES/FAMILIES AFFECTED:** DG9424EDN-T1-GE4, DG9424EDQ-T1-GE3, DG9425EDQ-T1-GE3, DG9426EDQ-T1-GE3,

**VISHAY BRAND(s):** Vishay Siliconix

**TIME SCHEDULE:**

Start Shipment Date: Mon Jan 23, 2023

**SAMPLE AVAILABILITY:** Now: 11/23/22

**PRODUCT IDENTIFICATION:** Date Code from 9/1/22

**QUALIFICATION DATA:** Comparison Data Attached

This PCN is considered approved, without further notification, unless we receive specific customer concerns before Mon Jan 23, 2023 or as specified by contract.

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## DG9424E/9425E/9426E Datasheet revision Comparison

### DG9424E, DG9425E, DG9426E Datasheet – Doc#75770

Revision C – June 2020

SPECIFICATIONS <sup>a</sup> Single Supply 3 V							
PARAMETER	SYMBOL	TEST CONDITIONS UNLESS OTHERWISE SPECIFIED V <sub>+</sub> = 3 V, V <sub>-</sub> = 0 V V <sub>L</sub> = 3 V, V <sub>IN</sub> = 2.4 V, 0.4 V <sup>f</sup>	TEMP. <sup>b</sup>	LIMITS -40 °C to +85 °C			UNIT
				MIN. <sup>d</sup>	TYP. <sup>c</sup>	MAX. <sup>d</sup>	
<b>Analog Switch</b>							
Analog signal range <sup>e</sup>	V <sub>ANALOG</sub>		Full	0	-	3	V
On-resistance	R <sub>ON</sub>	V <sub>+</sub> = 2.7 V, V <sub>-</sub> = 0 V. I <sub>NO</sub> , I <sub>NC</sub> = 5 mA, V <sub>COM</sub> = 0.5, 2.2 V	Room	-	6	-	Ω
			Full	-	-	-	
Switch off leakage current <sup>a</sup>	I <sub>NO(off)</sub>	V <sub>+</sub> = 3.3 V, V <sub>-</sub> = 0 V. V <sub>COM</sub> = 0.3, 3 V, V <sub>NO</sub> , V <sub>NC</sub> = 3, 0.3 V	Room	-1	-	1	nA
	I <sub>NC(off)</sub>		Full	-10	-	10	
	I <sub>COM(off)</sub>		Room	-1	-	1	
			Full	-10	-	10	
Channel on leakage current <sup>a</sup>	I <sub>COM(on)</sub>	V <sub>+</sub> = 3.3 V, V <sub>-</sub> = 0 V, V <sub>NO</sub> , V <sub>NC</sub> = V <sub>COM</sub> = 0.3, 3 V	Room	-1	-	1	nA
			Full	-10	-	10	
<b>Digital Control <sup>e</sup></b>							
Input current	I <sub>INL</sub> OR I <sub>INH</sub>		Full	-1	0.005	1	μA
<b>Dynamic Characteristics</b>							
Turn-on time	t <sub>ON</sub>	R <sub>L</sub> = 300 Ω, C <sub>L</sub> = 35 pF. V <sub>NO</sub> , V <sub>NC</sub> = 1.5 V, see Fig. 2	Room	-	140	-	ns
			Full	-	-	193	
Turn-off time	t <sub>OFF</sub>	V <sub>NO</sub> , V <sub>NC</sub> = 1.5 V, see Fig. 2	Room	-	65	-	ns
			Full	-	-	89	

Revision D – October 2022

SPECIFICATIONS <sup>a</sup> Single Supply 3 V							
PARAMETER	SYMBOL	TEST CONDITIONS UNLESS OTHERWISE SPECIFIED V <sub>+</sub> = 3 V, V <sub>-</sub> = 0 V V <sub>L</sub> = 3 V, V <sub>IN</sub> = 2.4 V, 0.4 V <sup>f</sup>	TEMP. <sup>b</sup>	LIMITS -40 °C to +85 °C			UNIT
				MIN. <sup>d</sup>	TYP. <sup>c</sup>	MAX. <sup>d</sup>	
<b>Analog Switch</b>							
Analog signal range <sup>e</sup>	V <sub>ANALOG</sub>		Full	0	-	3	V
On-resistance	R <sub>ON</sub>	V <sub>+</sub> = 2.7 V, V <sub>-</sub> = 0 V. I <sub>NO</sub> , I <sub>NC</sub> = 5 mA, V <sub>COM</sub> = 0.5, 2.2 V	Room	-	6	-	Ω
			Full	-	-	-	
Switch off leakage current <sup>a</sup>	I <sub>NO(off)</sub>	V <sub>+</sub> = 3.3 V, V <sub>-</sub> = 0 V. V <sub>COM</sub> = 0.3, 3 V, V <sub>NO</sub> , V <sub>NC</sub> = 3, 0.3 V	Room	-1	-	1	nA
	I <sub>NC(off)</sub>		Full	-10	-	10	
	I <sub>COM(off)</sub>		Room	-1	-	1	
			Full	-10	-	10	
Channel on leakage current <sup>a</sup>	I <sub>COM(on)</sub>	V <sub>+</sub> = 3.3 V, V <sub>-</sub> = 0 V, V <sub>NO</sub> , V <sub>NC</sub> = V <sub>COM</sub> = 0.3, 3 V	Room	-1	-	1	nA
			Full	-10	-	10	
<b>Digital Control <sup>e</sup></b>							
Input current	I <sub>INL</sub> OR I <sub>INH</sub>		Full	-1	0.005	1	μA
<b>Dynamic Characteristics</b>							
Turn-on time	t <sub>ON</sub>	R <sub>L</sub> = 300 Ω, C <sub>L</sub> = 35 pF. V <sub>NO</sub> , V <sub>NC</sub> = 1.5 V, see Fig. 2	Room	-	170	-	ns
			Full	-	-	230	
Turn-off time	t <sub>OFF</sub>	V <sub>NO</sub> , V <sub>NC</sub> = 1.5 V, see Fig. 2	Room	-	65	-	ns
			Full	-	-	89	

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Procedure #